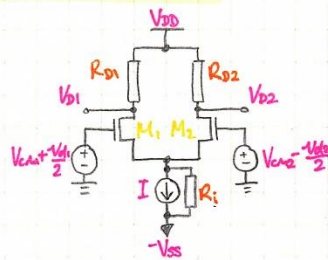
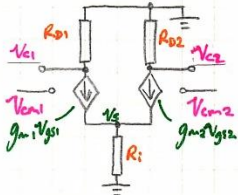


Differential Amplifier



Small Signal
Common Mode



If $R_{D1} = R_{D2} = R_D$, $g_{m1} = g_{m2} = g_m$, $V_{d1} = V_{d2} = V_d$

Common Mode

$$g_m V_{gs} + g_m V_{gs} = \frac{V_d}{R_D}$$

$$* V_{gs} = \frac{1}{2g_m R_D + 1} V_{cm}$$

If R_D large, $2g_m R_D \gg 1$

$$V_{gs} \approx \frac{1}{2g_m R_D} V_{cm}$$

$$g_m V_{gs} = \frac{1}{2R_D} V_{cm}$$

$$V_{d1} = V_{d2} = -\frac{R_D V_{cm}}{2R_D}$$

$$V_{d0} = V_{d1} - V_{d2} = 0$$

$$A_c = 0$$

If symmetrical EXCEPT $R_{D1} = R_D$, $R_{D2} = R_D + \Delta R_D$

Common Mode

$$* V_{gs} = \frac{1}{2g_m R_D + 1} V_{cm}$$

$$g_m V_{gs} = \frac{g_m}{2g_m R_D + 1} V_{cm}$$

$$V_{d1} = -\frac{g_m R_D}{2g_m R_D + 1} V_{cm}$$

$$V_{d2} = -\frac{g_m (R_D + \Delta R_D)}{2g_m R_D + 1} V_{cm}$$

$$V_{d0} = V_{d1} - V_{d2}$$

$$= -\frac{g_m \Delta R_D}{2g_m R_D + 1} V_{cm}$$

$$A_c = \frac{V_{d0}}{V_{cm}} = -\frac{g_m \Delta R_D}{2g_m R_D + 1}$$

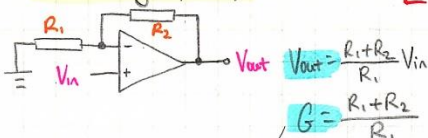
Operational Amplifiers (OP-amps)

$$V_o = A(V^+ - V^-)$$

ideal: $A = \infty$ $r_{out} = 0$
 $i^+ = i^- = 0$ $r_{in} = \infty$
 $V^+ - V^- = 0$ (virtual short)

Negative feedback \rightarrow output signal fed back into input

Non-inverting op-amp



$$V_{out} = \frac{R_1 + R_2}{R_1} V_{in}$$

$$G = \frac{R_1 + R_2}{R_1}$$

Common-mode rejection ratio (CMRR)

$$CMRR = \frac{A_D}{A_c}$$

A_D - Difference mode gain

A_c - Common mode gain

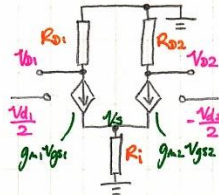
Difference mode signal

$$V_{D0} = V_{d1} - V_{d2}$$

Common mode signal

$$V_{C0} = \frac{V_{d1} + V_{d2}}{2}$$

Difference Mode



Difference Mode

$$g_m V_{gs1} + g_m V_{gs2} = \frac{V_d}{R_D}$$

$$g_m \left(\frac{V_d}{2} - V_s \right) + g_m \left(\frac{V_d}{2} - V_s \right) = \frac{V_d}{R_D}$$

$$-2g_m V_s = \frac{V_d}{R_D}$$

* g_m independent from R_D so $V_s = 0$

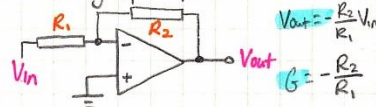
$$V_{d1} = -\frac{g_m R_D V_d}{2}$$

$$V_{d2} = \frac{g_m R_D V_d}{2}$$

$$V_{d0} = V_{d1} - V_{d2} = -g_m R_D V_d$$

$$A_D = \frac{V_{d0}}{V_d} = -g_m R_D$$

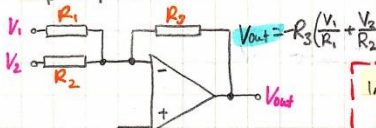
Inverting op-amp



$$V_{out} = -\frac{R_2}{R_1} V_{in}$$

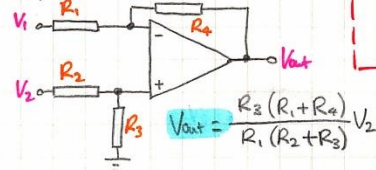
$$G = -\frac{R_2}{R_1}$$

Op-amp adder

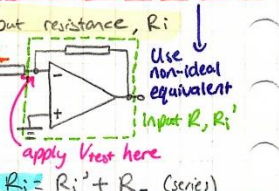
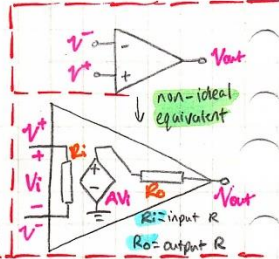


$$V_{out} = -R_3 \left(\frac{V_1}{R_1} + \frac{V_2}{R_2} \right)$$

Op-amp subtractor



$$V_{out} = \frac{R_2(R_1 + R_4)}{R_1(R_2 + R_3)} V_2 - \frac{R_4}{R_1} V_1$$



Op amp saturation
 $+V_E: A(V^+ - V^-) > +V_{cc}$
 $-V_E: A(V^+ - V^-) < -V_{cc}$

Energy Storage Elements:

Capacitors (Electrical Energy)

$$q(t) = C v(t)$$

$$i(t) = C \frac{dv(t)}{dt} \quad v(t) = \frac{1}{C} \int_{-\infty}^t i(t) dt$$

$$\text{Stored energy} = W_E(t) = \frac{q^2(t)}{2C} = \frac{C v(t)^2}{2}$$

Parallel Plate capacitor

$$C(t) = \frac{\epsilon A(t)}{L(t)}$$

Area A

Inductors (Magnetic Energy)

$$\lambda(t) = L i(t) \quad [\text{flux linkage}]$$

$$v(t) = L \frac{di(t)}{dt} \quad i(t) = \frac{1}{L} \int_{-\infty}^t v(t) dt$$

$$\text{Stored energy} = W_M(t) = \frac{\lambda^2(t)}{2L} = \frac{L i(t)^2}{2}$$

Inductor

$$L(t) = \frac{\mu N^2 A(t)}{l(t)}$$

Area A

Combinations

Capacitors		Inductors	
Series	Parallel	Series	Parallel
$\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2}$	$C_{eq} = C_1 + C_2$	$L_{eq} = L_1 + L_2$	$\frac{1}{L_1} = \frac{1}{L_1} + \frac{1}{L_2}$

Capacitor

\hookrightarrow discharged \rightarrow short

\hookrightarrow fully charged \rightarrow open

\hookrightarrow $v(t)$ continuous

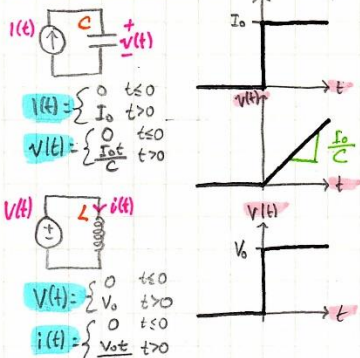
Inductor

\hookrightarrow discharged \rightarrow open

\hookrightarrow fully charged \rightarrow short

\hookrightarrow $i(t)$ continuous

Step functions



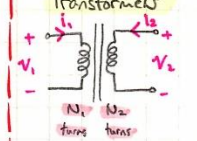
MOSFET Gate Capacitance

$$C_{gs} = \frac{\epsilon_{ox} L W}{d}$$

$$C_{ox} = \frac{\epsilon_{ox}}{d}$$

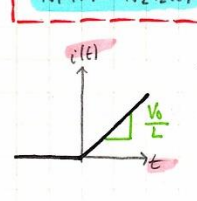
$$C_{gs} = C_{ox} L W$$

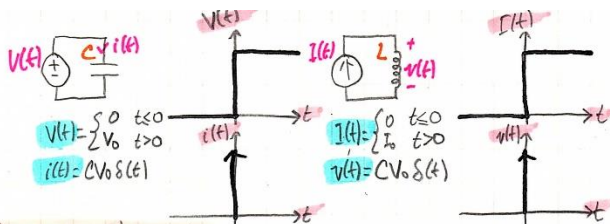
Transformers



$$\frac{V_1(t)}{N_1} = \frac{V_2(t)}{N_2}$$

$$N_1 i_1(t) = -N_2 i_2(t)$$

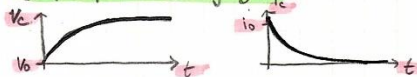




First order transients

Capacitor (RC circuits)

Step response (charging)



$$\text{Form: } V_c(t) = A(1 - e^{-t/\tau})$$

$$i_c(t) = B e^{-t/\tau}$$

Natural response (discharging)

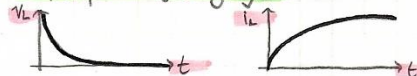


$$\text{Form: } V_c(t) = A e^{-t/\tau}$$

$$i_c(t) = -B e^{-t/\tau}$$

Inductor (RL circuits)

Step response (charging)



$$\text{Form: } V_c(t) = A e^{-t/\tau}$$

$$i_c(t) = B(1 - e^{-t/\tau})$$

Natural response (discharging)



$$\text{Form: } V_c(t) = -A e^{-t/\tau}$$

$$i_c(t) = B e^{-t/\tau}$$

RC circuits

$$\tau = RC$$

RL circuits

$$\tau = \frac{L}{R}$$

Typically (dis)charges

$$\frac{1}{2} = 36.8\%$$

in 1τ

$\%$ Fully (dis)charges in 5τ

Zero input response

↳ non-zero initial conditions

↳ input drive is zero

Zero state response

↳ zero initial conditions

↳ non-zero input drive

Total response

$$\text{ZIR} + \text{ZSR}$$

How to solve First order transients

- 1) Find homogeneous solution (natural response)
- 2) Find particular solution (forced/driven response)
- 3) Solution = homogeneous sltn + particular sltn.
- 4) Apply initial conditions
- ↳ Apply Kirchhoff's to get differential eq.
- ↳ Set constants = 0 → homogeneous sltn.
- ↳ Sub homogeneous sltn into diff eq. w/ constants → Method of undetermined coefficients → add unknown K
- ↳ Sub in initial conditions

E storage in equivalent components

If two capacitors, C_1, C_2 make C_{eq}

$$V_{c1}(t) + V_{c2}(t) = V_{ceq}(t)$$

$$V_{c1}(t) = A_1 e^{-t/\tau} + B$$

$$V_{c2}(t) = A_2 e^{-t/\tau} - B$$

$$V_{ceq} = (A_1 + A_2) e^{-t/\tau}$$

If two inductors L_1, L_2 make L_{eq}

$$i_{L1}(t) + i_{L2}(t) = i_{Leq}(t)$$

$$i_{L1}(t) = A_1 e^{-t/\tau} + B$$

$$i_{L2}(t) = A_2 e^{-t/\tau} - B$$

$$i_{Leq} = (A_1 + A_2) e^{-t/\tau}$$

If two storage elements of same type. $X_1, X_2 \rightarrow X_{eq}$

X_{eq} Fully charges / discharges as $t \rightarrow \infty$

$$[E_{x1}(0) + E_{x2}(0)] - E_{x_{eq}}(0) = [E_{x1}(\infty) + E_{x2}(\infty)]$$

initial E in both elements
initial E in eq element
E trapped in both elements

General form of equations:

Capacitor

$$V_c(t) = V_c(\infty) + [V_c(0) - V_c(\infty)] e^{-t/\tau}$$

$$V_c(t) = V_c(0) e^{-t/\tau} + V_c(\infty) (1 - e^{-t/\tau})$$

Inductor

$$i_L(t) = i_L(\infty) + [i_L(0) - i_L(\infty)] e^{-t/\tau}$$

$$i_L(t) = i_L(0) e^{-t/\tau} + i_L(\infty) (1 - e^{-t/\tau})$$

Propagation delay (gate delay)

↳ time for circuit to reliably output desired output



$t_{pd1 \rightarrow 0}$ 1→0 change at INPUT

$t_{pd0 \rightarrow 1}$ 0→1 change at INPUT



Rise time: 0→1 change at OUTPUT

Fall time: 1→0 change at OUTPUT



$$t_{pd} = \max(t_{pd1 \rightarrow 0}, t_{pd0 \rightarrow 1})$$

for multiple input/output:

input/output pair $i \rightarrow t_{pd}^{ii}$

$$t_{pd} = \max_i t_{pd}^{ii}$$

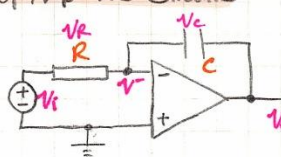
State Variables

$$\frac{d}{dt}(\text{state variable}) = f(\text{state variable}, \text{input variable})$$

If linear:

$$\frac{d}{dt}(\text{state variable}) = K_1(\text{state variable present value}) + K_2(\text{input variable})$$

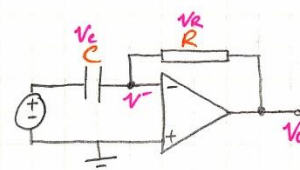
Op Amp RC Circuits



Integrator

$$V_c = -\frac{1}{RC} \int V_i dt$$

$$V_o \approx -\frac{1}{RC} \int V_i dt$$



Differentiator

$$V_R = -RC \frac{dV_c}{dt}$$

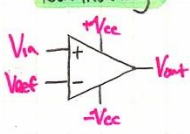
$$V_o \approx -RC \frac{dV_i}{dt}$$

Op amp positive feedback

↳ turn continuous analog signals into 2 state signals

Comparator

Non-inverting



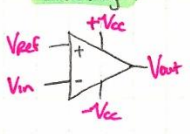
If $V_{in} > V_{ref}$

$V_{out} = +V_{cc}$

If $V_{in} < V_{ref}$

$V_{out} = -V_{cc}$

Inverting



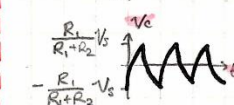
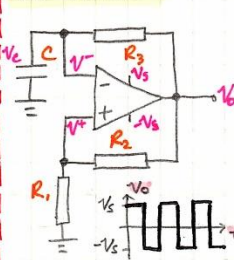
If $V_{in} > V_{ref}$

$V_{out} = -V_{cc}$

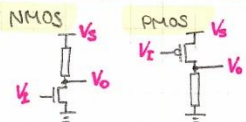
If $V_{in} < V_{ref}$

$V_{out} = +V_{cc}$

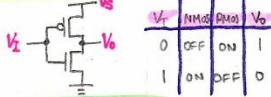
RC oscillator



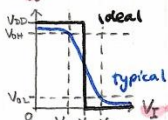
Inverter circuits - triode (MOSFET)



CMOS



Transfer Curve



$$V_T = V_{TN} + \sqrt{\frac{K_p}{K_n}} (V_S + V_{TP})$$

When $I_{DN} = I_{DP}$

Unified Model

NMOS $V_T > 0$

$$i_{DS} = \begin{cases} 0 & V_{GS} < V_T \\ K \left[\frac{V_{GS} - V_T}{2} V_{DS} - \frac{V_{DS}^2}{2} \right] & V_{GS} \geq V_T, V_{DS} < V_{GS} - V_T \\ \frac{K}{2} (V_{GS} - V_T)^2 & V_{GS} \geq V_T, V_{DS} \geq V_{GS} - V_T \end{cases}$$

PMOS $V_T < 0$

$$i_{SD} = \begin{cases} 0 & V_{SG} < |V_T| \\ K \left[\frac{V_{SG} - |V_T|}{2} V_{SD} - \frac{V_{SD}^2}{2} \right] & V_{SG} \geq |V_T|, V_{SD} < V_{SG} - |V_T| \\ \frac{K}{2} (V_{SG} - |V_T|)^2 & V_{SG} \geq |V_T|, V_{SD} \geq V_{SG} - |V_T| \end{cases}$$

$$K = \mu C_{ox} \frac{W}{L}$$

SR Model

$$i_D = \frac{V_{DS}}{R_{on}} \quad R_{on} = R_n \frac{L}{W}$$

under triode conditions

set $\begin{cases} \mu = \text{mobility} \\ C_{ox} = \text{capacitance per area of gate oxide} \\ W = \text{MOSFET width} \\ L = \text{MOSFET length} \end{cases}$ designed

NMOSFETs in parallel
↳ Act as 1 MOSFET w/ dimensions K_n
↳ $K_n = NK_0$
↳ K_0 - dimensions of 1
↳ allows for greater I

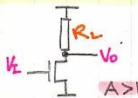
Diode connected MOSFET



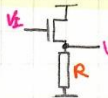
Always in saturation: $V_{DS} = V_{GS}$
Small signal: $i_{DS} = \frac{V_{GS}}{g_m V_{GS}} = \frac{1}{g_m}$

Amplifiers - saturation (MOSFET)

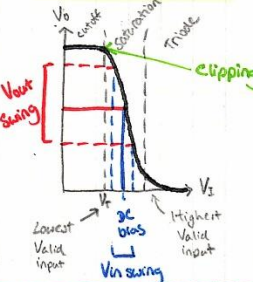
Common source



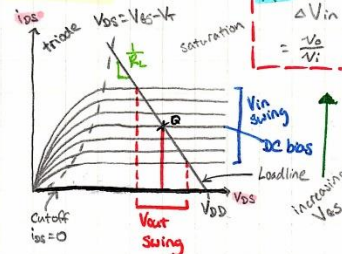
Common drain



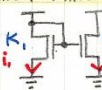
MOSFET transfer curve



IV Curve



Current Mirror

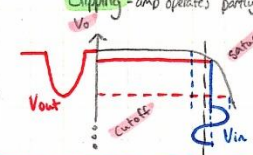


$$\frac{i_2}{i_1} = \frac{K_2}{K_1}$$

SS Gain

$$A = \frac{\Delta V_{out}}{\Delta V_{in}} = \frac{V_o}{V_i}$$

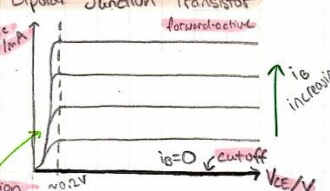
Clipping - amp operates partly in cutoff



Highest Valid Input

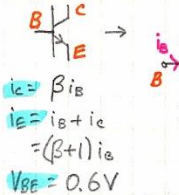
$$V_{inmax} = -1 + \sqrt{1 + 2V_{DD}R_LK}$$

Bipolar Junction Transistor



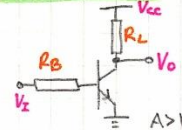
Mode	E-B Junction	C-B Junction
Cutoff	Reverse	Reverse
Active	Forward	Reverse
Saturation	Forward	Forward

Equivalent circuit



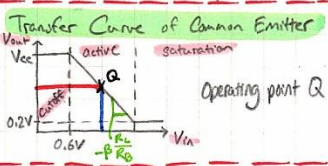
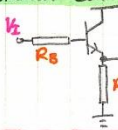
Amplifiers (BJT)

Common Emitter



$$\begin{aligned} i_B &= \frac{V_B - 0.6}{R_B} \\ i_E &= \beta i_B \\ i_C &= (\beta + 1) i_B \\ V_O &= V_{CC} - i_C R_L \\ &= V_{CC} - \beta \frac{R_L}{R_B} (V_B - 0.6) \end{aligned}$$

Common Collector



Small Signal Analysis

MOSFET

$$V_{GS} = V_{GS} + v_{gs}$$

$$i_D = \frac{I_D}{DC} + \frac{i_d}{AC/SS}$$

$$i_D = \frac{K}{2} (V_{GS} - V_T)^2 + K (V_{GS} - V_T) v_{gs}$$

$$i_d = K (V_{GS} - V_T) v_i = g_m v_i$$

$$g_m = \text{transconductance} = K (V_{GS} - V_T)$$

Input/Output Resistance (SS)

↳ set independent V_i, I_i sources = 0
↳ Use SS model → apply test at input/output

$$r = \frac{V_{test}}{I_{test}}$$

MOSFET amplifier - common source

$$r_i \approx \infty$$

$$r_o = R_L$$

MOSFET amplifier - common drain

$$r_i \approx \infty$$

$$r_o \approx \frac{1}{g_m}$$

BJT amplifier - common emitter

$$r_i = R_B$$

$$r_o = R_L$$

BJT amplifier - common collector

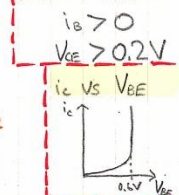
$$r_i = R_B + (\beta + 1) R_E$$

$$r_o \approx \frac{R_E}{\beta + 1}$$

Equivalent Models

Component	Large signal	Small signal
MOSFET		
Resistor		
Vsource		
I source		
Capacitor		
Inductor		
Block Box		
Block Box		

Forward Active



Common Source

$$\begin{aligned} V_{out} &= V_{out} + V_{out} \\ &= V_{DD} - I_D R_L - i_d R_L \end{aligned}$$

$$\begin{aligned} V_{out} &= -i_d R_L \\ &= -g_m R_L v_{gs} \\ A &= \frac{V_{out}}{V_{in}} = -g_m R_L \end{aligned}$$

Current gain

$$\begin{aligned} \text{Current gain} &= \frac{i_o}{i_i} \\ &= \frac{\text{incremental } i \text{ output}}{\text{incremental } i \text{ input}} \end{aligned}$$

Power gain

$$\begin{aligned} \text{Power gain} &= \frac{P_{out}}{P_{in}} \\ &= \frac{V_o i_o}{V_i i_i} \\ &= |g_{ain}| \times |g_{vain}| \end{aligned}$$